

FEATURES

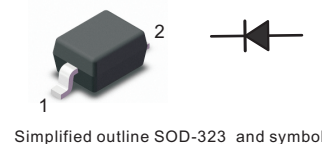
- For surface mounted applications
- Glass Passivated Chip Junction
- Fast reverse recovery time
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SOD-323
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 5.48mg / 0.00019oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Simplified outline SOD-323 and symbol

Absolute Maximum Ratings at 25 °C

Parameter	Symbols	1N4148WS T4	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Maximum RMS voltage	V_{RMS}	75	V
Average Rectified Forward Current	$I_{F(AV)}$	150	mA
Non-repetitive Peak Forward Surge Current at 1s at 1ms at 1us	I_{FSM}	0.5 1 4	A
Total Power Dissipation	P_{tot}	400	mW
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150	°C

Characteristics at $T_a = 25\text{ °C}$

Parameter	Symbols	1N4148WS T4	Units
Reverse Breakdown Voltage at $I_R = 1\mu A$	$V_{(BR)R}$	75	V
Maximum Forward Voltage at 1 mA at 10 mA at 50 mA at 150 mA	V_F	0.715 0.855 1.00 1.25	V
Peak Reverse Current at $V_R = 20V$ $T_j = 25\text{ °C}$ at $V_R = 75V$ $T_j = 25\text{ °C}$ at $V_R = 25V$ $T_j = 150\text{ °C}$ at $V_R = 75V$ $T_j = 150\text{ °C}$	I_R	0.025 1 30 50	μA
Typical Junction Capacitance $f = 1MHz, V_R = 0V$	C_j	2	pF
Maximum Reverse Recovery Time ⁽¹⁾	t_{rr}	4	ns

(1) Measured with $I_F = I_R = 10mA, I_{rr} = 0.1 \times I_R, R_L = 100\Omega$

Fig.1 Power Derating Curve

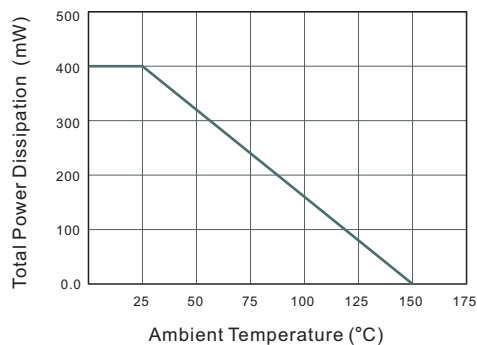


Fig.2 Typical Reverse Characteristics

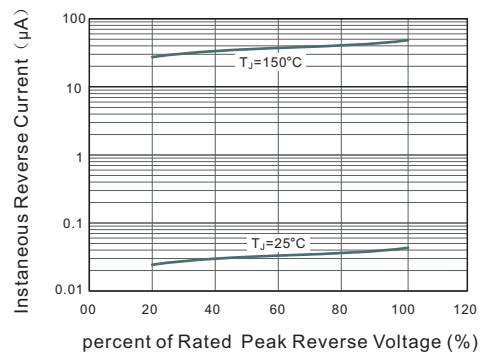


Fig.3 Typical Instaneous Forward Characteristics

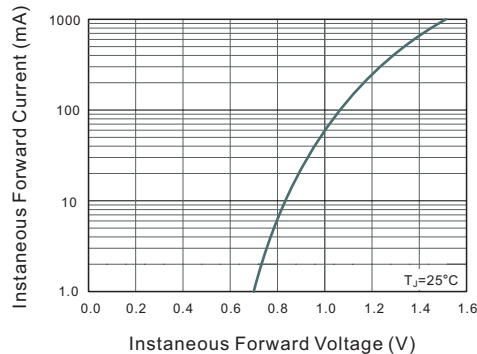
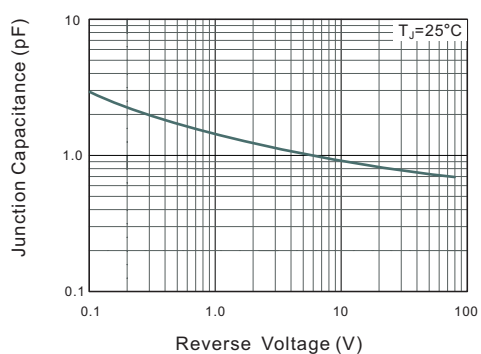


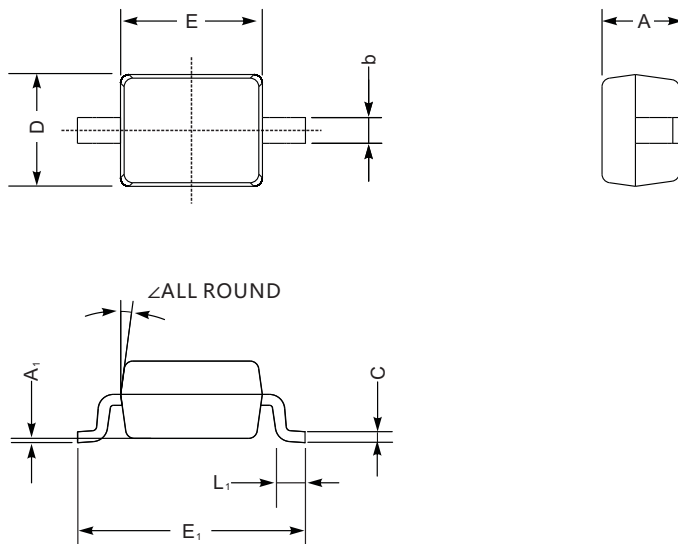
Fig.4 Typical Junction Capacitance



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



SOD-323 mechanical data

UNIT		A	C	D	E	E ₁	b	L ₁	A ₁	∠
mm	max	1.1	0.15	1.4	1.8	2.75	0.4	0.45	0.2	9°
	min	0.8	0.08	1.2	1.4	2.55	0.25	0.2	—	
mil	max	43	5.9	55	70	108	16	16	8	
	min	32	3.1	47	63	100	9.8	7.9	—	

The recommended mounting pad size

